

BS250PSTOB Datasheet



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DiGi Electronics Part Number BS250PSTOB-DG

Manufacturer Diodes Incorporated

Manufacturer Product Number BS250PSTOB

Description MOSFET P-CH 45V 230MA E-LINE

Detailed Description P-Channel 45 V 230mA (Ta) 700mW (Ta) Through H

ole E-Line (TO-92 compatible)



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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: | | | |
|-----------------------------------------|-----------------------------------------|--|--|--|
| BS250PSTOB | Diodes Incorporated | | | |
| Series: | Product Status: | | | |
| Jenes. | | | | |
| | Obsolete | | | |
| FET Type: | Technology: | | | |
| P-Channel | MOSFET (Metal Oxide) | | | |
| Drain to Source Voltage (Vdss): | Current - Continuous Drain (Id) @ 25°C: | | | |
| 45 V | 230mA (Ta) | | | |
| Drive Voltage (Max Rds On, Min Rds On): | Rds On (Max) @ Id, Vgs: | | | |
| 10V | 140hm @ 200mA, 10V | | | |
| Vgs(th) (Max) @ ld: | Vgs (Max): | | | |
| 3.5V @ 1mA | ±20V | | | |
| Input Capacitance (Ciss) (Max) @ Vds: | FET Feature: | | | |
| 60 pF @ 10 V | | | | |
| Power Dissipation (Max): | Operating Temperature: | | | |
| 700mW (Ta) | -55°C ~ 150°C (TJ) | | | |
| Mounting Type: | Supplier Device Package: | | | |
| Through Hole | E-Line (TO-92 compatible) | | | |
| Package / Case: | Base Product Number: | | | |
| E-Line-3 | BS250 | | | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| LITCIIC. | |

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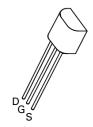


BS250P

P-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Features and Benefits

- V_{DS} = 45V
- R_{DS(ON)} = 14Ω
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
- https://www.diodes.com/quality/product-definitions/



E-Line TO92 Compatible

REFER TO ZVP2106A FOR GRAPHS

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|----------------------------------------------------|------------------|-------------|------|
| Drain-Source Voltage | VDS | -45 | V |
| Continuous Drain Current at T _A = +25°C | ID | -230 | mA |
| Pulsed Drain Current | Ідм | -3 | Α |
| Gate Source Voltage | Vgs | ± 20 | V |
| Power Dissipation at T _A = +25°C | Ртот | 700 | mW |
| Operating and Storage Temperature Range | T_{J}, T_{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--------------------------------------------------|---------------------|-----|-----|------|----------|---------------------------------------------|--|
| Drain-Source Breakdown Voltage | BV _{DSS} | -45 | 1 | _ | > | $I_D = -100 \mu A, V_{GS} = 0V$ | |
| Gate-Source Threshold Voltage | V _{GS(TH)} | -1 | - | -3.5 | V | $I_D = -1 \text{mA}, V_{DS} = V_{GS}$ | |
| Gate-Body Leakage | IGSS | _ | _ | -20 | nA | $V_{GS} = -15V$, $V_{DS} = 0V$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | _ | 1 | -500 | nA | $V_{GS} = 0V, V_{DS} = -25V$ | |
| Static Drain-Source On-State Resistance (Note 1) | R _{DS(ON)} | _ | _ | 14 | Ω | $V_{GS} = -10V, I_D = -200mA$ | |
| Forward Transconductance (Note 1) (Note 2) | 9fs | _ | 150 | _ | ms | $V_{DS} = -10V, I_{D} = -200mA$ | |
| Input Capacitance (Note 2) | C _{iss} | _ | 60 | _ | pF | $V_{GS} = 0V, V_{DS} = -10V,$ f = 1.0MHz | |
| Turn-On Time (Note 2) (Note 3) | t _(ON) | _ | _ | 20 | ns | V 25V I 500mA | |
| Turn-Off Time (Note 2) (Note 3) | t _(OFF) | _ | _ | 20 | ns | $V_{DD} \approx -25V$, $I_D = -500$ mA | |

Notes:

- 1. Measured under pulsed conditions. Pulse Width = 300 µs. Duty cycle ≤2%.
- 2. Sample test.
- 3. Switching times measured with a 50Ω source impedance and <5ns rise time on a pulse generator.



BS250P

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